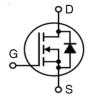


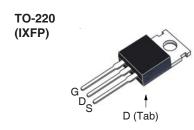
# X3-Class HiPerFET™ **Power MOSFET**

# **IXFP130N15X3** IXFH130N15X3

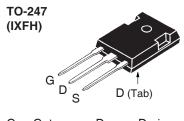
150V 130A  $9.0 m\Omega$ 

N-Channel Enhancement Mode Avalanche Rated





Symbol	Test Conditions	Maximum Ra	atings
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 150°C	150	V
V <sub>DGR</sub>	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M $\Omega$	150	V
V <sub>GSS</sub>	Continuous	±20	V
V <sub>GSM</sub>	Transient	±30	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	130	Α
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	230	Α
I <sub>A</sub>	T <sub>C</sub> = 25°C	65	Α
E <sub>AS</sub>	$T_{c} = 25^{\circ}C$	1.2	J
dv/dt	$I_{S} \le I_{DM}, V_{DD} \le V_{DSS}, T_{J} \le 150^{\circ}C$	50	V/ns
$P_{D}$	T <sub>c</sub> = 25°C	390	W
T <sub>J</sub>		-55 +150	°C
$T_{JM}$		150	°C
T <sub>stg</sub>		-55 +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
M <sub>d</sub>	Mounting Torque	1.13 / 10	Nm/lb.in
Weight	TO-220 TO-247	3 6	g g



G = Gate	D	= Drair
S = Source	Tab	= Drain

#### **Features**

- International Standard Packages
- Low  $R_{\rm DS(ON)}$  and  $Q_{\rm G}$  Avalanche Rated
- Low Package Inductance

#### **Advantages**

- High Power Density
- Easy to Mount
- Space Savings

## **Applications**

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- · Robotics and Servo Controls

Symbol (T <sub>J</sub> = 25°C,	Test Conditions Unless Otherwise Specified)	Charac Min.	cteristic	Values   Max	ζ.
BV <sub>DSS</sub>	$V_{GS} = 0V, I_{D} = 250\mu A$	150			V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 1.5 \text{mA}$	2.5		4.5	V
I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ , $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			5 300	μ <b>Α</b> μ <b>Α</b>
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$		7.6	9.0	mΩ



Symbol	Test Conditions	<b>Characteristic Values</b>		
$(T_{J} = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max
g <sub>fs</sub>	$V_{DS} = 10V, I_{D} = 60A, Note 1$	50	82	S
$R_{Gi}$	Gate Input Resistance		1.8	Ω
C <sub>iss</sub>			5230	pF
C <sub>oss</sub>	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		920	pF
C <sub>rss</sub>			14	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		585	pF
$C_{o(tr)}$	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		1350	pF
t <sub>d(on)</sub>	Resistive Switching Times		21	ns
t,	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_{D} = 0.5 \cdot I_{D25}$		25	ns
t <sub>d(off)</sub>			62	ns
t, )	$R_{\rm g} = 5\Omega$ (External)		12	ns
$Q_{g(on)}$			80	nC
Q <sub>gs</sub>	$V_{GS} = 10V$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$		27	nC
$\mathbf{Q}_{gd}$			25	nC
R <sub>thJC</sub>				0.32 °C/W
$\mathbf{R}_{thCS}$	TO-220		0.50	°C/W
	TO-247		0.21	°C/W

### Source-Drain Diode

Symbol $(T_J = 25^{\circ}C,$	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
I <sub>s</sub>	V <sub>GS</sub> = 0V			130	Α
I <sub>SM</sub>	Repetitive, Pulse Width Limited by $T_{_{\rm JM}}$			520	Α
V <sub>SD</sub>	$I_F = I_S$ , $V_{GS} = 0V$ , Note 1			1.4	V
t <sub>rr</sub> Q <sub>RM</sub> }	$I_F = 65A$ , -di/dt = 100A/ $\mu$ s $V_R = 100V$		80 230 5.7		ns nC A

Note 1. Pulse test,  $t \le 300 \mu s$ , duty cycle,  $d \le 2\%$ .



Fig. 1. Output Characteristics @ T<sub>J</sub> = 25°C

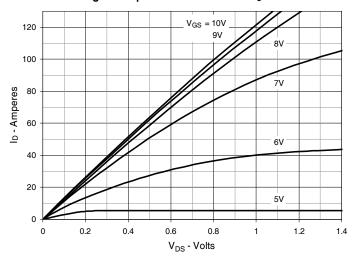


Fig. 2. Extended Output Characteristics @  $T_J = 25^{\circ}C$ 

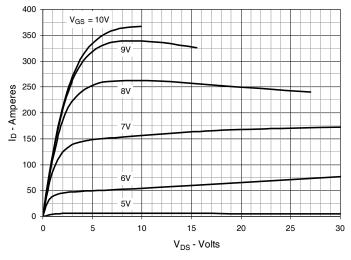


Fig. 3. Output Characteristics @ T<sub>J</sub> = 125°C

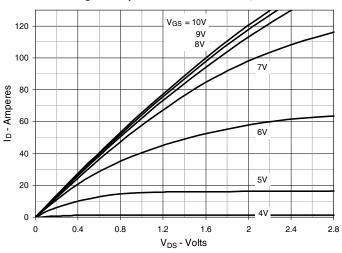


Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D$  = 65A Value vs. Junction Temperature

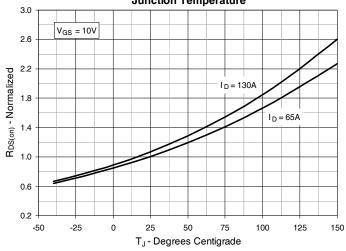


Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D$  = 65A Value vs.

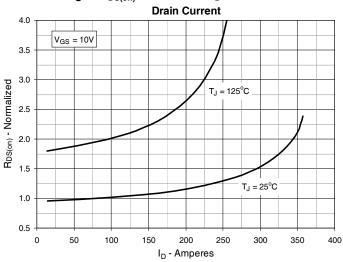
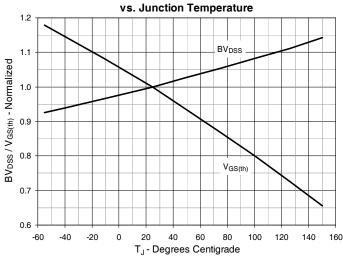
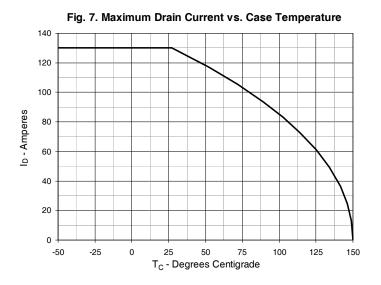
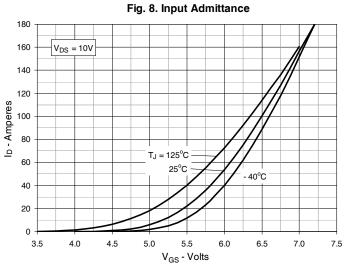


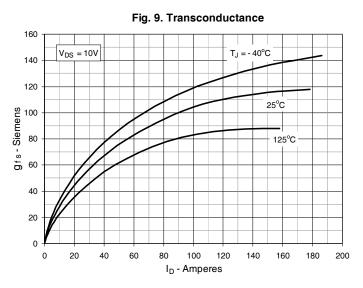
Fig. 6. Normalized Breakdown & Threshold Voltages

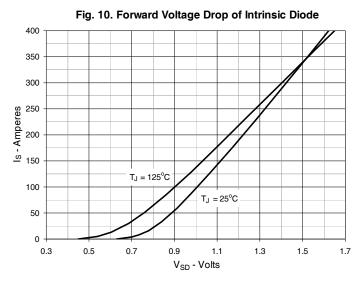


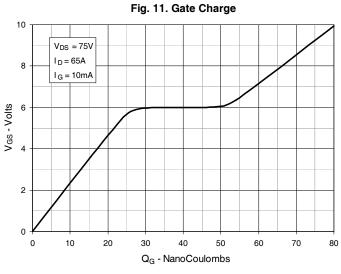


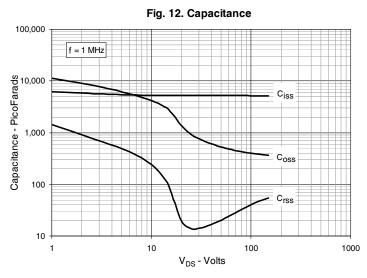






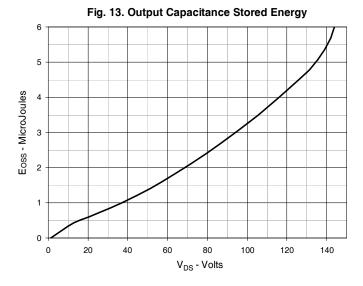


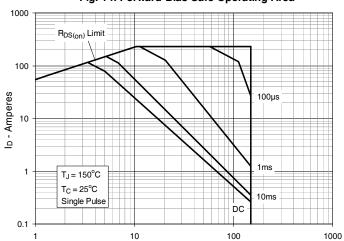




IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



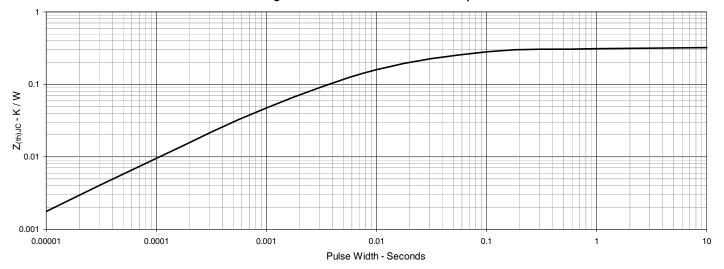




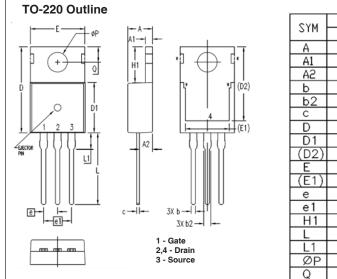
V<sub>DS</sub> - Volts

Fig. 14. Forward-Bias Safe Operating Area

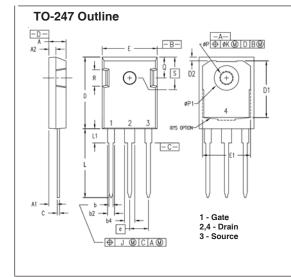








SYM	INCHES		MILLIMETERS	
21M	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ь	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
С	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
Ε	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
Ф	.100 BSC		2.54	BSC
e1	.200	) BSC	5.08 BSC	
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



SYM	INCH	łES	MILLIMETERS	
STIVI	MIN	MAX	MIN	MAX
Α	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
Ь	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
С	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
Е	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
е	.215 BSC		5.45	BSC
J		.010		0.25
K		.025		0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
ØΡ	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242	BSC	6.15 BSC	





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